

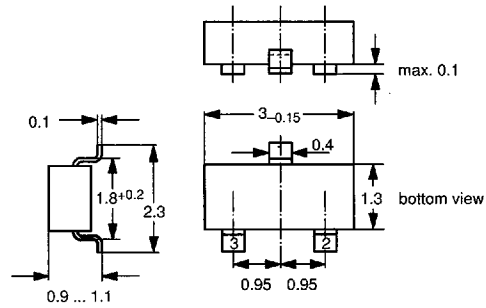
# DTA114EK

## PNP Digital Transistor

with built-in bias resistor. This allows inverter circuit configuration without external resistors for input.

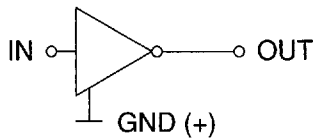
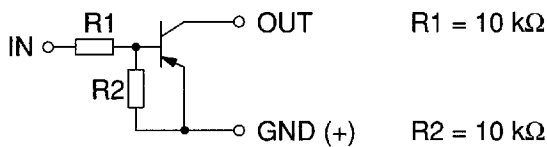
The pin configuration is the following:

- 1 = Collector/OUT
- 2 = Base/IN
- 3 = Emitter/GND



Plastic Package JEDEC TO-236  
23 A 3 according to DIN 41869  
The case is impervious to light.

Weight approximately 0.008 g  
Dimensions in mm



Equivalent circuit

## Absolute Maximum Ratings

	Symbol	Value	Unit
Supply Voltage	$-V_{SUP}$	50	V
Input Voltage	$-V_I$	40	V
	$V_I$	10	V
Collector Current	$-I_C$	50	mA
Peak Collector Current	$-I_{CM}$	100	mA
Power Dissipation	$P_{tot}$	200 <sup>1)</sup>	mW
Junction Temperature	$T_j$	125	°C
Storage Temperature Range	$T_S$	-55 to +125	°C

<sup>1)</sup> Device on fiberglass substrate 30 mm x 10 mm, pad size 2 mm x 2 mm

Characteristics at  $T_{amb} = 25\text{ }^{\circ}\text{C}$ 

	Symbol	Min.	Typ.	Max.	Unit
Input OFF Voltage at $-V_{SUP} = 5\text{ V}$ , $-I_O = 100\text{ }\mu\text{A}$	$-V_{I(OFF)}$	0.5	–	–	V
Input ON Voltage at $-V_O = 0.3\text{ V}$ , $-I_O = 10\text{ mA}$	$-V_{I(ON)}$	–	–	3.0	V
Output ON Voltage at $-I_O = 10\text{ mA}$ , $-I_I = 0.5\text{ mA}$	$-V_{O(ON)}$	–	0.1	0.3	V
Input Current at $V_I = 5\text{ V}$ ,	$-I_I$	–	–	0.88	V
Output OFF Current at $-V_{SUP} = 30\text{ V}$ , $V_I = 0\text{ V}$	$-I_{O(OFF)}$	–	–	10	$\mu\text{A}$
DC Current Gain at $-I_O = 5\text{ mA}$ , $-V_O = 5\text{ V}$	$G_I$	30	–	–	–
Input Resistance	$R_I$	–	10	–	$\text{k}\Omega$
Resistance Ratio	$R_2/R_1$	0.8	1	1.2	–
Transition Frequency at $-V_{CE} = 10\text{ V}$ , $I_E = 5\text{ mA}$	$f_T$	–	250	–	MHz
Collector Base Capacitance at $-V_{CB} = 10\text{ V}$ , $I_E = 0\text{ mA}$ , $f = 1\text{ MHz}$	$C_{ob}$	–	4.7	–	pF
Switching Times at $-V_{SUP} = 5\text{ V}$ , $-V_I = 5\text{ V}$ , $R_L = 1\text{ k}\Omega$					
Rise Time	$t_r$	–	0.06	–	$\mu\text{s}$
Storage Time	$t_s$	–	1.1	–	$\mu\text{s}$
Fall Time	$t_f$	–	0.24	–	$\mu\text{s}$